

ST8812FX

High voltage fast-switching NPN Power transistor

Features

- High voltage capability
- Very high switching speed
- Tight hfe control
- Large R.B.S.O.A.
- Fully insulated Package U.L. compliant for easy mounting

Applications

■ Switch mode power supplies for crt TV

Description

The ST8812FX is manufactured using latest Multi Epitaxial Planar technology with high voltage capability. It shows wide R.B.S.O.A. and high switching speed thanks to its Cellular Emitter structure with planar edge termination and deep base diffusion.



Internal schematic diagram



Order codes

Part Number	Marking	Package	Packing
ST8812FX	ST8812FX	ISOWATT218FX	TUBE

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www.st.com

1 Electrical ratings

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage (I _E = 0)	1150	V
V _{CEO}	Collector-Emitter Voltage (I _B = 0)	600	V
V _{EBO}	Emitte-Base Voltage (I _C = 0)	15	V
۱ _C	Collector Current	7	А
I _{CM}	Collector Peak Current (t _P < 5ms)	12	А
I _B	Base Current	4	А
P _{TOT}	Total dissipation at $T_c = 25^{\circ}C$	50	W
V _{isol}	Insulation Withstand Voltage (RMS) from All Three Leads to External Heatsink	2500	V
T _{STG}	Storage Temperature	-65 to 150	°C
Tj	Max. Operating Junction Temperature	150	°C

Table 1. Absolute maximum rating

Table 2.Thermal data

Symbol	Parameter	Value	Unit
R _{thJ-case}	Thermal Resistance Junction-Case Max	2.5	°C/W



2 Electrical characteristics

(T_{CASE} = 25°C; unless otherwise specified)

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
I _{CES}	Collector Cut-off Current (V _{BE} = 0)	V _{CE} = 1150V V _{CE} = 1150V	T _c = 125°C			1 2	mA mA
I _{EBO}	Emitter Cut-off Current $(I_{\rm C} = 0)$	V _{EB} = 14V				1	mA
V _{CEO(sus)} Note: 1	Collector-Emitter Sustaining Voltage (I _B = 0)	I _C = 100mA		600			V
V _{CE(sat)} <i>Note: 1</i>	Collector-Emitter Saturation Voltage	$I_{\rm C} = 4A$ $I_{\rm C} = 4A$	I _B = 0.8A I _B = 1.2A			3 1.5	V V
V _{BE(sat)} Note: 1	Base-Emitter Saturation Voltage	I _C = 4A	I _B = 0.8A			1.3	V
h _{FE}	DC Current Gain	$I_{C} = 1A$ $I_{C} = 5A$ $I_{C} = 5A$	V _{CE} = 5V V _{CE} = 1V V _{CE} = 5V	4.5	25 5	9	
t _s t _f	INDUCTIVE LOAD Storage Time Fall Time	I _C = 4A V _{Clamp} = 480V I _{B1} = 0.8A (See <i>Figure 8</i>)	R _{BB} = 0 V _{BE(off)} = -5V L _C = 220μH		1 60	1.6 120	μs ns

 Table 3.
 Electrical characteristics

Note: 1 Pulsed duration = $300 \,\mu$ s, duty cycle $\leq 1.5\%$.



GC63940

T_J = 25°C

h_{FE}=5

I_c(A)

2.1 Typical characteristics test circuit

Figure 1. DC current gain

Figure 2. DC current gain





V_{BE(sat)} (V)

1

0.8

0.6

0.4

0.2

0

 10^{-1}









T_J = 125 °C



10⁰

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Figure 7. Reverse biased S.O.A.







Figure 8. Inductive load switching test circuit

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3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK[®] packages. These packages have a Lead-free second level interconnect. The category of second Level Interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.



DIM.	mm			inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А	5.30		5.70	0.209		0.224	
С	2.80		3.20	0.110		0.126	
D	3.10		3.50	0.122		0.138	
D1	1.80		2.20	0.071		0.087	
E	0.80		1.10	0.031		0.043	
F	0.65		0.95	0.026		0.037	
F2	1.80		2.20	0.071		0.087	
G	10.30		11.50	0.406		0.453	
G1		5.45			0.215		
Н	15.30		15.70	0.602		0.618	
L	9.0		10.20	0.354		0.402	
L2	22.80		23.20	0.898		0.913	
L3	26.30		26.70	1.035		1.051	
L4	43.20		44.40	1.701		1.748	
L5	4.30		4.70	0.169		0.185	
L6	24.30		24.70	0.957		0.972	
L7	14.60		15.00	0.575		0.591	
Ν	1.80		2.20	0.071		0.087	
R	3.80		4.20	0.150		0.165	
DIA	3 40		3.80	0 134		0 150	

ISOWATT218FX MECHANICAL DATA



4 Revision History

Date	Revision	Changes
23-Feb-2006	1	Initial release.



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